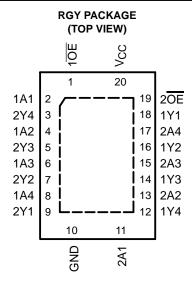
SCES432 - MARCH 2003

- Optimized for 1.8-V Operation and is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Sub 1-V Operable
- Max t<sub>pd</sub> of 1.9 ns at 1.8 V
- Low Power Consumption, 20-μA Max I<sub>CC</sub>
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



# description/ordering information

This octal buffer/driver is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.65-V to 1.95-V  $V_{CC}$  operation.

The SN74AUC244 is organized as two 4-bit line drivers with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is low, the device passes data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### **ORDERING INFORMATION**

TA	PACKAC	e†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RGY	Tape and reel	SN74AUC244RGYR	MS244

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

# FUNCTION TABLE (each 4-bit buffer/driver)

INP	JTS	OUTPUT
OE	Α	Y
L	Н	Н
L	L	L
Н	Χ	Z

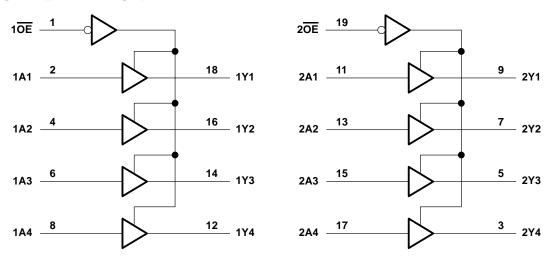


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SCES432 - MARCH 2003

### logic diagram (positive logic)



# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	
Voltage range applied to any output in the high-impedance or power-off state, V <sub>O</sub>	
(see Note 1)	–0.5 V to 3.6 V
Output voltage range, V <sub>O</sub> (see Note 1)	–0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Continuous output current, I <sub>O</sub>	±20 mA
Continuous current through V <sub>CC</sub> or GND	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2):	37°C/W
Storage temperature range, T <sub>stg</sub>	$-65^{\circ}$ C to $150^{\circ}$ C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-5.



# recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage		0.8	2.7	V
		$V_{CC} = 0.8 \text{ V}$	Vcc		
$V_{IH}$	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	0.65 × V <sub>CC</sub>		V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		
		$V_{CC} = 0.8 \text{ V}$		0	
$V_{IL}$	Low-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	
۷Į	Input voltage		0	3.6	V
\/-	Output voltage	Active state	0	VCC	V
۷O	O Output voltage	3-state	0	3.6	l v
		V <sub>CC</sub> = 0.8 V		-0.7	
		V <sub>CC</sub> = 1.1 V		-3	
loH	High-level output current	V <sub>CC</sub> = 1.4 V		<b>-</b> 5	mA
		V <sub>CC</sub> = 1.65 V		-8	
		V <sub>CC</sub> = 2.3 V		-9	
		V <sub>CC</sub> = 0.8 V		0.7	
		V <sub>CC</sub> = 1.1 V		3	
loL	Low-level output current	V <sub>CC</sub> = 1.4 V		5	mA
		V <sub>CC</sub> = 1.65 V		8	
		V <sub>CC</sub> = 2.3 V	5		
Δt/Δν	Input transition rise or fall rate	-		20	ns/V
TA	Operating free-air temperature		-40	85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



# SN74AUC244 OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES432 - MARCH 2003

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

P.	ARAMETER	TEST CONDITION	ONS	vcc	MIN	TYP†	MAX	UNIT		
		I <sub>OH</sub> = -100 μA		0.8 V to 2.7 V	V <sub>CC</sub> -0.	1				
		$I_{OH} = -0.7 \text{ mA}$		0.8 V		0.55				
\ <sub>\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\</sub>		$I_{OH} = -3 \text{ mA}$		1.1 V	0.8			V		
VOH		$I_{OH} = -5 \text{ mA}$		1.4 V	1			V		
		$I_{OH} = -8 \text{ mA}$		1.65 V	1.2					
		$I_{OH} = -9 \text{ mA}$		2.3 V	1.8					
		$I_{OL} = 100 \mu\text{A}$		0.8 V to 2.7 V			0.2			
		$I_{OL} = 0.7 \text{ mA}$		0.8 V		0.25				
\ <sub>\\ \</sub> .		I <sub>OL</sub> = 3 mA		1.1 V			0.3	V		
VOL		$I_{OL} = 5 \text{ mA}$		1.4 V			0.4	」 ゛ l		
		I <sub>OL</sub> = 8 mA		1.65 V			0.45			
		I <sub>OL</sub> = 9 mA		2.3 V			0.6			
IĮ	A and OE inputs	$V_I = V_{CC}$ or GND		0 to 2.7 V			±5	μΑ		
l <sub>off</sub>		$V_I$ or $V_O = 2.7 V$		0			±10	μΑ		
loz		$V_O = V_{CC}$ or GND		2.7 V			±10	μΑ		
Icc		$V_I = V_{CC}$ or GND,	I <sub>O</sub> = 0	0.8 V to 2.7 V			20	μΑ		
Ci		$V_I = V_{CC}$ or GND	_	2.5 V		2	3	pF		
Co		$V_O = V_{CC}$ or GND		2.5 V		5.5	6	pF		

<sup>&</sup>lt;sup>†</sup> All typical values are at  $T_A = 25$ °C.

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 15 pF (unless otherwise noted) (see Figure 1)

P	PARAMETER FROM TO (OUTPUT)		V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> =		V <sub>CC</sub> =			c = 1.8 0.15 V		V <sub>CC</sub> = ± 0.		UNIT	
				TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
	<sup>t</sup> pd	А	Y	6.5	1.1	3.7	0.6	2.3	0.5	1.1	1.9	0.4	1.5	ns
	t <sub>en</sub>	ŌĒ	Y	8	1.2	4.5	0.7	2.8	0.6	1.2	2.3	0.5	1.7	ns
	<sup>t</sup> dis	ŌĒ	Υ	10.4	1.7	6	1.1	4	1.7	2.4	4.2	0.6	3.8	ns

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 30 pF (unless otherwise noted) (see Figure 1)

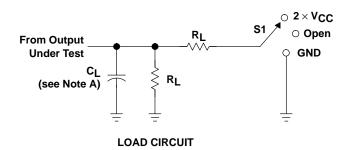
PARAMETER	FROM (INPUT)	TO (OUTPUT)		c = 1.8 0.15 V		V <sub>CC</sub> =		UNIT			
	(INFOT)	(001F01)	MIN	TYP	MAX	MIN	MAX				
<sup>t</sup> pd	Α	Υ	0.8	1.5	2.5	0.7	1.9	ns			
t <sub>en</sub>	ŌĒ	Υ	0.8	1.7	3.1	0.7	2.3	ns			
<sup>t</sup> dis	ŌĒ	Y	1.7	2.4	4.2	0.5	2.3	ns			



# operating characteristics, $T_A = 25^{\circ}C$

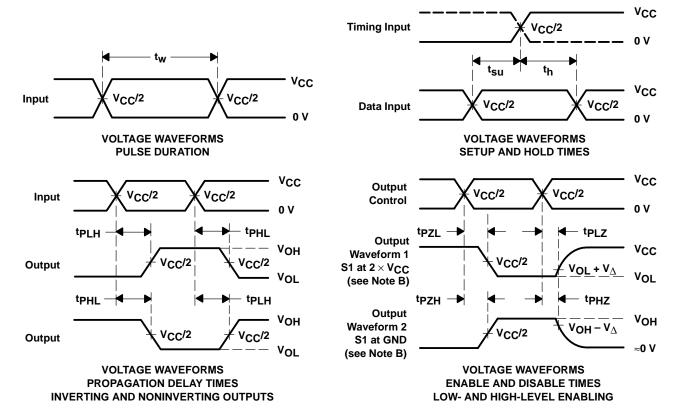
PARAMETER		TEST	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = 1.5 V	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	UNIT	
	TANAMETE		CONDITIONS	TYP	TYP	TYP	TYP	TYP	ONIT
C <sub>pd</sub>	Power	Outputs enabled	f = 10 MHz	21	21	22	23	30	pF
Сра	dissipation capacitance	Outputs disabled	1 = 10 WHZ	3	3	3	3.5	4.5	рг

#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	2×V <sub>CC</sub>
tPHZ/tPZH	GND

Vcc	CL	RL	$v_{\scriptscriptstyle\Delta}$
0.8 V	15 pF	<b>2 k</b> Ω	0.1 V
1.2 V ± 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.5 V ± 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.8 V $\pm$ 0.15 V	15 pF	<b>2 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	15 pF	<b>2 k</b> Ω	0.15 V
1.8 V ± 0.15 V	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	30 pF	500 Ω	0.15 V



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.

    Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ , slew rate  $\geq$  1 V/ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. tpLz and tpHz are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





## PACKAGE OPTION ADDENDUM

11-Apr-2013

#### PACKAGING INFORMATION

Orderable Device		Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
SN74AUC244RGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MS244	Samples
SN74AUC244RGYRG4	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MS244	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

# PACKAGE MATERIALS INFORMATION

www.ti.com 26-Jan-2013

## TAPE AND REEL INFORMATION





A0	
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUC244RGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

www.ti.com 26-Jan-2013



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUC244RGYR	VQFN	RGY	20	3000	367.0	367.0	35.0

3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (<a href="www.ti.com/legal/termsofsale.html">www.ti.com/legal/termsofsale.html</a>) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2019, Texas Instruments Incorporated